Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Metal
Overall Length:
0.030 inches
Terminal Length:
1.000 inches
Overall Diameter:
0.450 inches
Electrode Internally-electrically Connected To Case: Cathode
Mounting Method: Terminal
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
100.0 reverse voltage, peak
Current Rating Per Characteristic:
3.00 amperes forward current, average absolute
Power Rating Per Characteristic:
4.0 watts small-signal input power, common-collector preset
Maximum Operating Tempurature Per Measurement Point:
175.0 degrees celsius junction
Terminal Type And Quantity:
2 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
-
Demilitarization:
No
Fiig:
A110a0